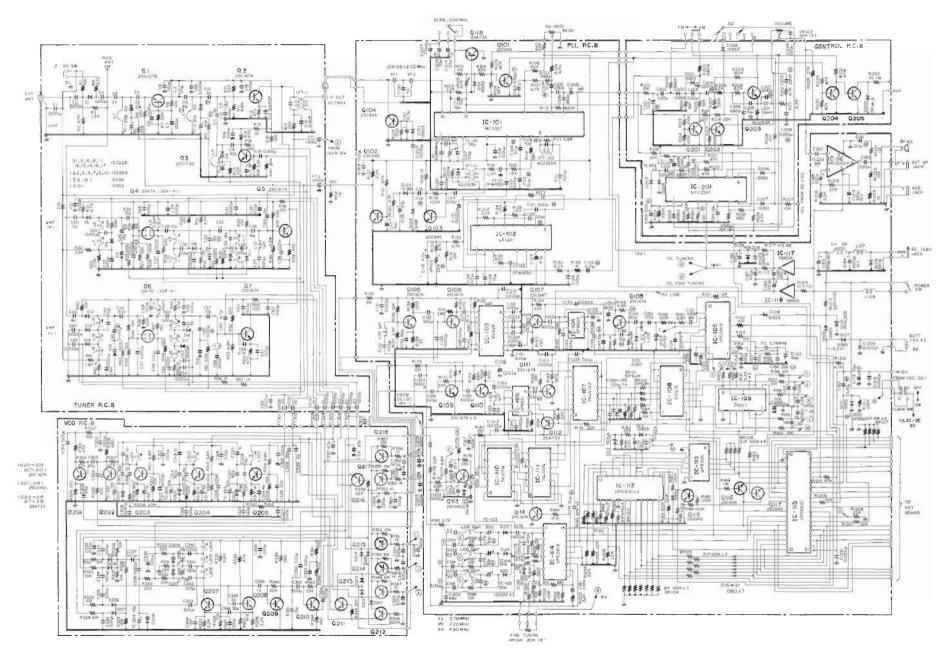
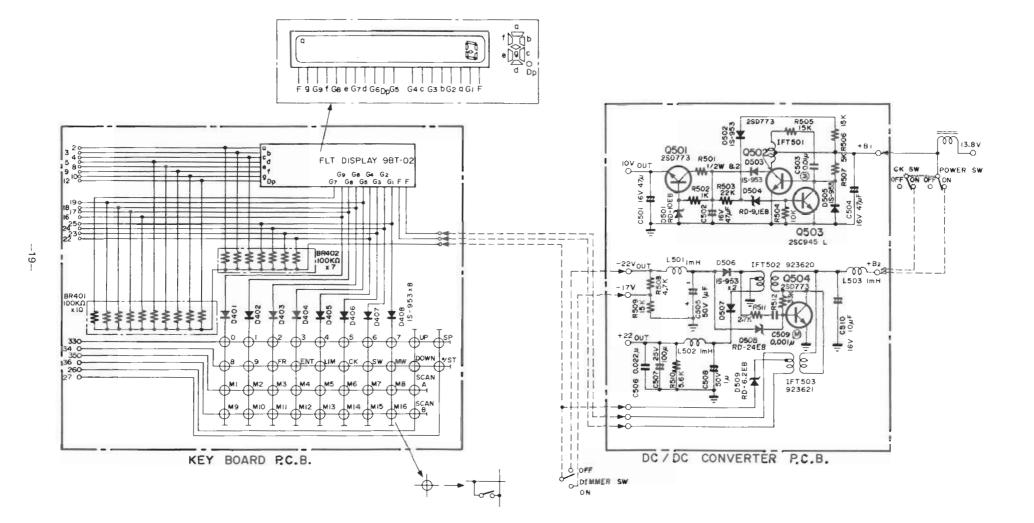


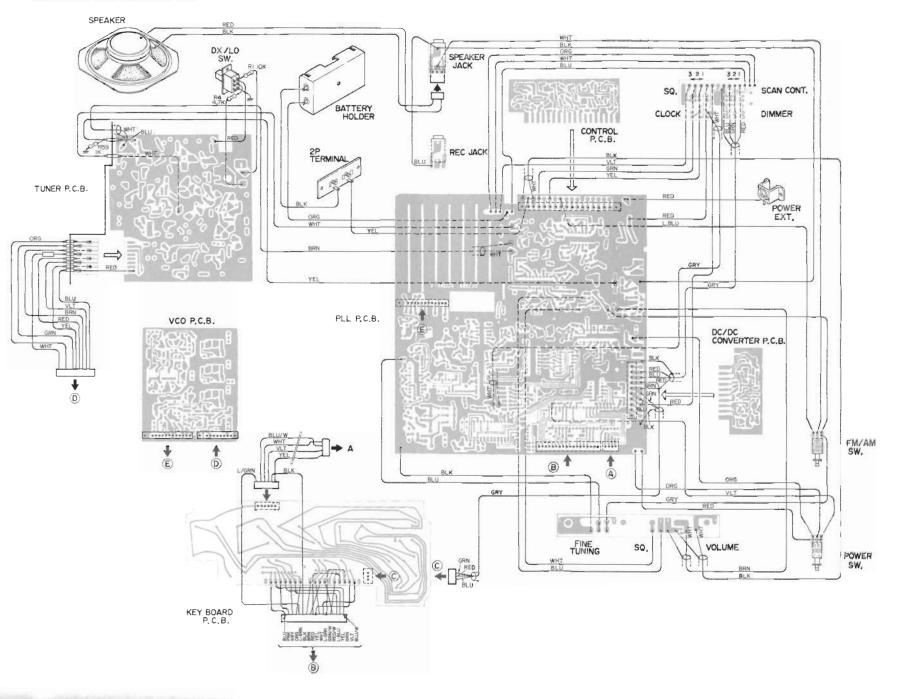
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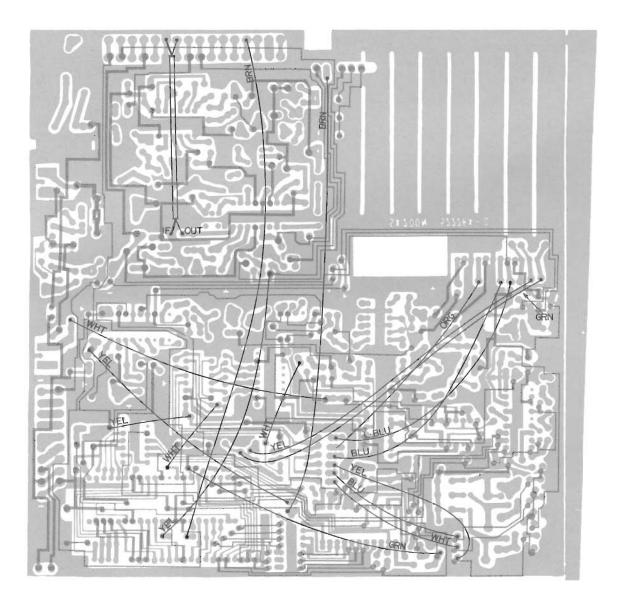


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PART LOCATION

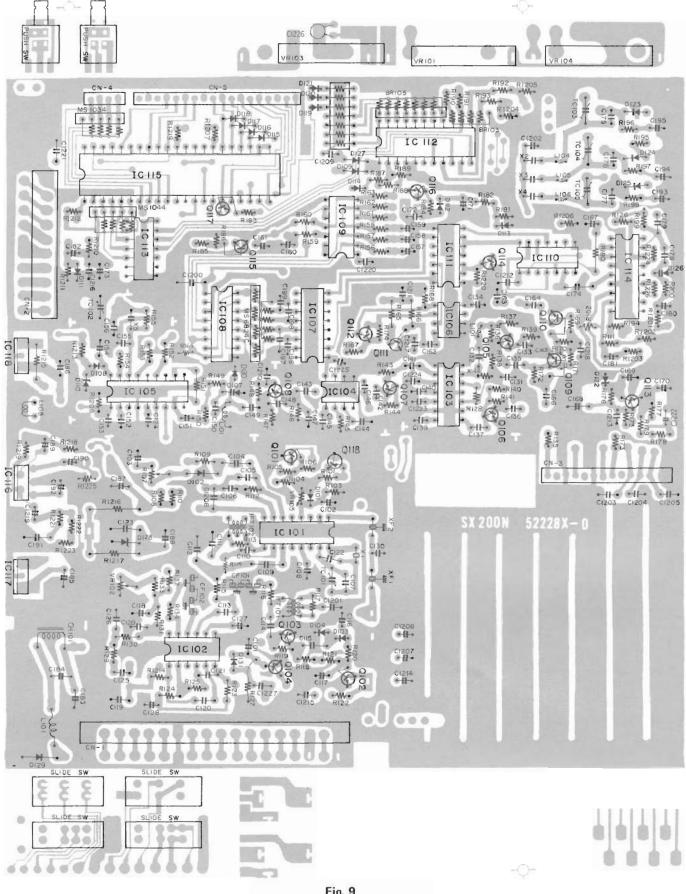


Fig. 9 PLL P.C. BOARD, WIRING SIDE

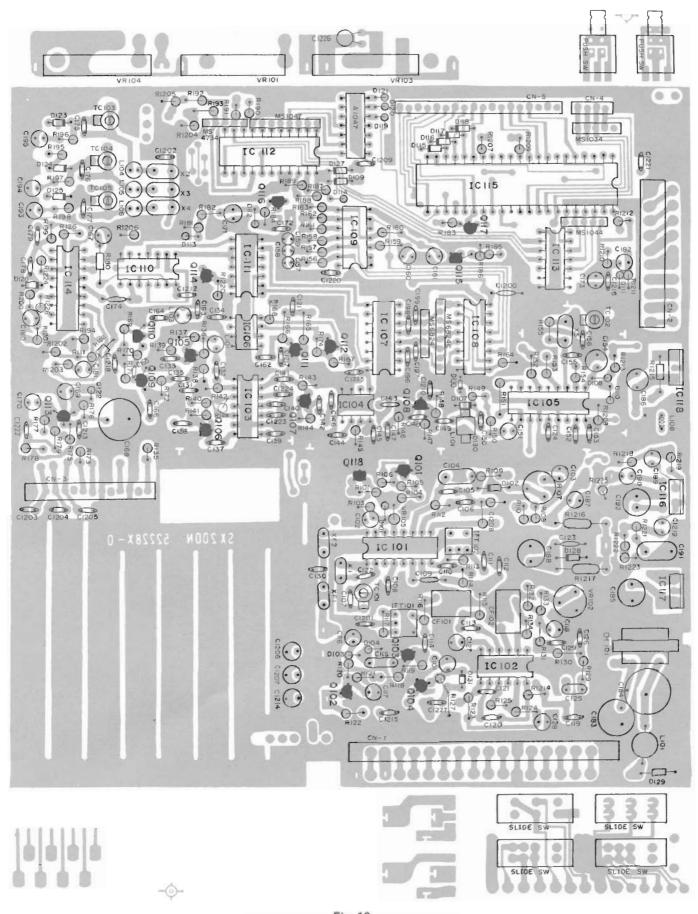
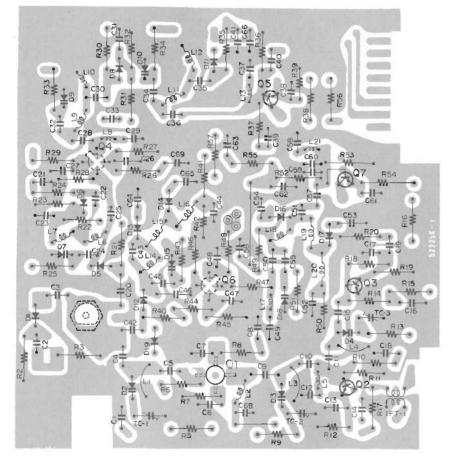


Fig. 10 PLL P.C. BOARD, COMPONENT SIDE



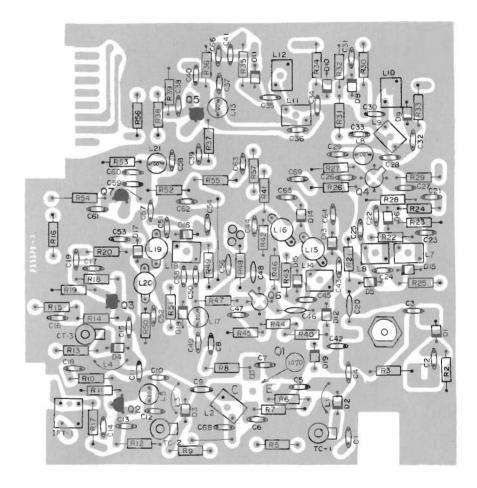
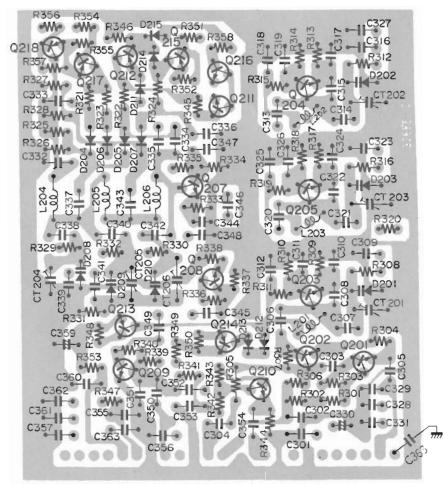


Fig. 11 TUNER P.C. BOARD, COMPONENT/WIRING SIDES



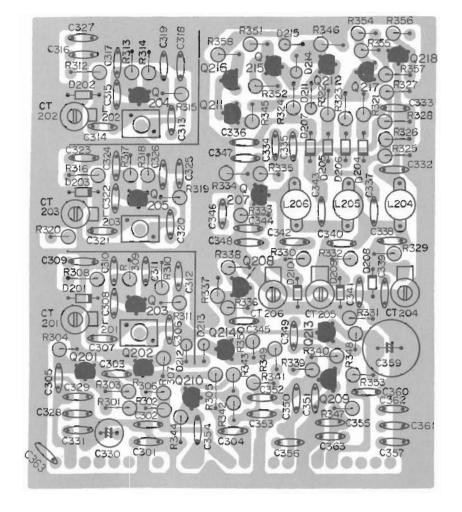
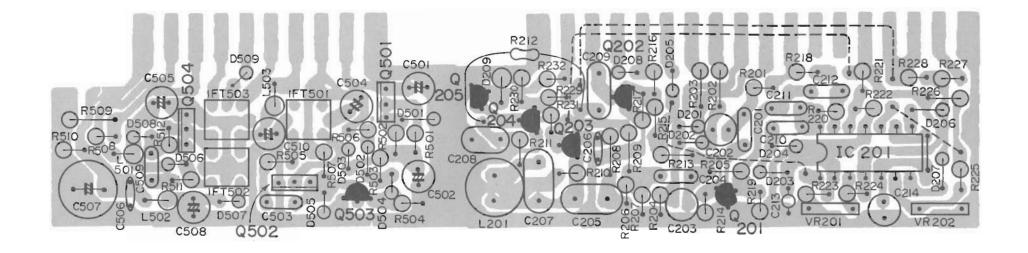
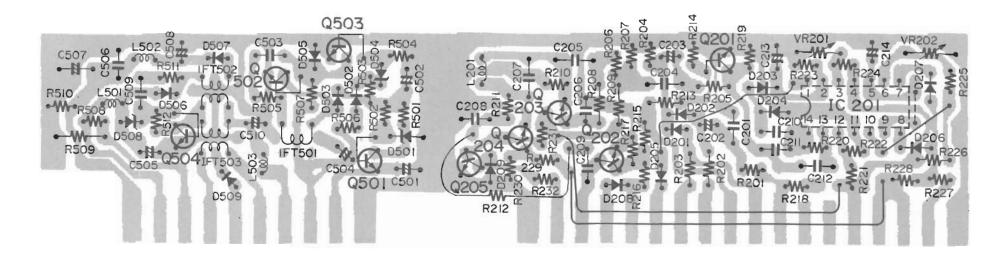


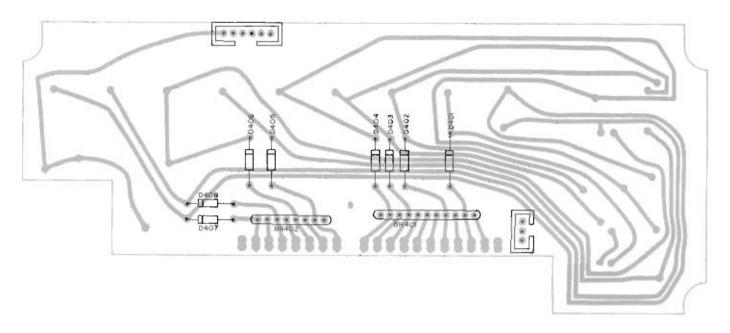
Fig. 12 VCO P.C. BOARD, COMPONENT/WIRING SIDES



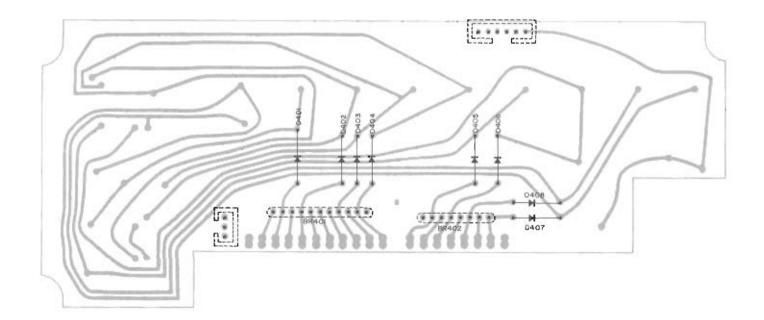


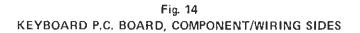
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Fig. 13 CONTROL P.C. BOARD, COMPONENT/WIRING SIDES DC-DC CONVERTER P.C. BOARD, COMPONENT/WIRING SIDES



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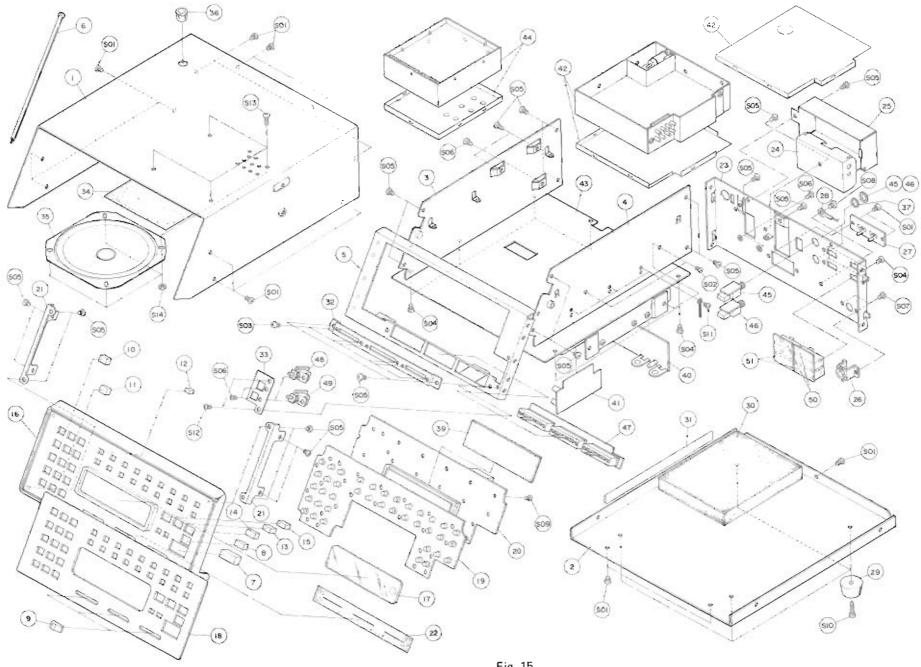


Fig. 15 ASSEMBLING LAYOUT (Final Assembling)

COMPONENT LIST (FINAL ASSEMBLING)

Ref. No.	Part No.	Description	Q'ty	Ref. No.	Part No.	Description	Q'ty
1	46588	Case, Top	1	34	46594	Dust Cover, Speaker	1
2	45897	Case, Bottom	1	35	924003	Speaker	1
3	46587	Side Plate, Left	1	36	923681	Bushing, Antenna	1
4	46586	Side Plate, Right	1	37	46595	Jack Spacer	2
5	46303	Case, Front	1	38		No component	
6	924029	Antenna	1	39	42239	Foam Rubber	1
7	45901	Knob, Push (POWER)	1	40	31589-1	Control P.C. Board Ass'y	1 1
8	46301	Knob, FM-AM	1	41	31589-2	DC/DC Converter P.C. Board Ass'y	1
9	45783	Knob, Slide (FINE TUNING/	3	42	31590	Tuner P.C. Board Ass'y	1
		SQUELCH/VOLUME)		43	31591	PLL P.C. Board Ass'y	1
10	45920	Knob, Channel A, FIGURES 0 thru. 9	10	44	31592	VCO P.C. Board Ass'y	1
11	46534	Knob, Channel B, ST/FR/LIM/ENT/SP	5	45	924004	External Speaker Jack	1
12	45782	Knob, Memory/SW-M/MW-H/	20	46	924004	REC Jack	1
		UP-DOWN Seek		47		Volume Board Ass'y	1
13	46601	Knob, SCAN A	1			Consists of 915581 (Volume)	
14	46602	Knob, SCAN B	1			915580 (Fine Tuning)	
15	46300	Knob, CK	1			915594 (Squelch)	
16	45741	Escutcheon	1	48	912122	Push Switch, FM-AM	1
17	45910	Window	1	49	912122	Push Switch, POWER	1
18	46302	Plate, Escutcheon	1	50	912123	Slide Switch, SCAN CONT./SQ.	1
19	45780	Rubber Contact	1	51	912124	Slide Switch, DIMMER/CLOCK	1
20	32667	Print Board, Keyboard	1			1000A 2000317	
20	923553	Digitron 9BT-02A		S01	023154	Screw M3 x 4, BH	15
21	45903	Bracket, Escutcheon	2	S02	023143	Screw 3 x 8, RH Tapping	2
22	45911	VR Shield Plate	1	S03	022027	Screw M2 x 4, BH	6
23	46585	Rear Plate	1	S04	022655	Screw M2.6 x 4, Truss	10
24	923907	Battery Holder	1	S05	023055	Screw M3 x 4, BH	22
25	46589	Battery Cover	1	S06	022655	Screw M2.6 x 4, Truss	5
26	923629	External Power Supply Jack	1	S07	022046	Screw M2 x 4, RH	2
27	923908	2P Screw Terminal	1	S08	024021	Screw M4 x 4, BH	1
28	922439	Ground Lead Wire	1	\$09	021702	Screw 1.7 x 4.6, BH	24
29	922163	Rubber Foot	4	S10	023108	Screw M3 x 8, BH	4
30 •	46600	Cushion Rubber	1	S11	022602	Screw M2.6 x 4, RH	3
31		Tape	2	S12	022678	Screw M2.6 x 3, Truss	2
32	45902	Bracket, VR	1	S13	023145	Screw M3 x 6, BH	4
33	46304	Bracket, Switch	1	S14	013003	Nut M3, Chrome	4

ELECTRICAL COMPONENT LIST

1. CONTROL P.C. BOARD

Ref. No.	Part No.	Description	Q'ty
SEMI-CONDU	CTORS 8	COIL	
IC201	916228	IC uPC324C	1
0201, 202, 203	916158	Silicon Transistor 2SC945L	3
0204, 205	916162	Silicon Transistor 2SC2001	2
D201 thru, 208	923147	Diode IS953	8
D209	923817	Diode SR1K-2	1
L201	913622	Micro Inductor 33mH	1
•		watt 10% tolerance unless	
otherwise spec	ified.		1.
otherwise spec R201	fied. 915015	10K ohm	1
otherwise spec R201 R202, 203	ified.	10K ohm 680K "	1 2 2
otherwise spec R201 R202, 203 R204, 205	fied. 915015 915483	10K ohm 680K "	2
otherwise spec R201 R202, 203 R204, 205 R206	fied. 915015 915483 915372	10K ohm 680K " 56K "	2
RESISTORS, a otherwise speci R201 R202, 203 R204, 205 R206 R207 R208	fied. 915015 915483 915372 915055	10K ohm 680K « 56K « 8.2K «	2
otherwise spec R201 R202, 203 R204, 205 R206 R207	fied. 915015 915483 915372 915055 915344	10K ohm 680K * 56K * 8.2K * 220K *	2
otherwise spec R201 R202, 203 R204, 205 R206 R207 R208	fied. 915015 915483 915372 915055 915344 915055	10K ohm 680K * 56K * 8.2K * 220K * 8.2K *	2

Ref. No,	Part No.	Des	cription	Q'ty
B212	915327	4.7K ohm		1
R213, 214	915039	100K "		2
R215, 216	915342	22K "		2
R217	915039	100K "		1
R218	915342	22K "		1
R219	915039	100K "		1
R220	915483	680K "		1
R221, 222	915343	47K ~		2
R223	915443	330K "		1
R224	915039	100K "		1
R225	915337	680 "		1
R226	915327	4.7K "		1
R227, 228	915015	10K "		2
R229, 230, 231	915343	47K "		3
R232	915106	1 "	(J) 1/2 watt	1
CAPACITORS otherwise spec		50 working	voltage unless	
C201	913020	Mylar	0.01uF	1
C202	913110	Electrolytic	0.47uF	1
C203	913583		0.22uF (NP)	1

1. CONTROL P.C. BOARD

Ref. No.	Part No.		Description	Qʻty
C204	913044	Mylar	0.047uF	1
C205	913021	Mylar	0.1uF	1
C206	913162	Ceramic	680pF	1
C207	913044	Mylar	0.047uF	1
C208	913550	Mylar	0.033uF	1
C209	913044	Mylar	0.047uF	1
C210	913020	Mylar	0.01uF	1
C211	913210	Mylar	0.0015uF	1

Ref, No.	Part No.	Description	Q'ty
C212	913220	Mylar 0.015uF	1
C213	913509	Aluminum 0.22uF	1
C214	913175	Electrolytic 10uF	1
VR201	915464	Semi-Fixed Volume 100 ohm (B)	1
VR202	915585	Semi-Fixed Volume 10K ohm (B)	1

2. DC-DC CONVERTER P.C. BOARD & KEYBOARD

Ref. No.	Part No.	Description	Q'ty		
SEMI-CONDUC	CTORS 8	COILS			
Q501, 502	916234	Silicon Transistor 2SD773	2		
Q503	916158	Silicon Transistor 2SC945	1		
Q504	916234	Silicon Transistor 2SD773	1		
D501	923687	Diode RD10EB	1		
D502, 503	923147	Diode IS953	2		
D504	923586	Diode RD9.1B	1		
D505, 506, 507	923147	Diode IS953	3		
D508	923587	Diode RD24EB	1		
D509	923588	Diode RD6.2EB	1		
D401 thru, 408	923147	Diode IS953 (Kyeboard)	8		
L501, 502, 503	913623	MicroInductor 1mH	3		
IFT501	923952	Coil 7BR-4824N	1		
IFT502	923620	Coil L-5K7H5	1		
IFT503	923621	Coil L-5K7H5	1		
RESISTORS, all are 1/8 watt 10% tolerance unless otherwise specified.					
R501	915322	1K "	1		
R502	915003		1		
R503	915342		7		
R504	915015		1		

Ref. No.	Part No.	Description	Qʻty
R505	915335	390 ohm	1
R506, 507	915341	15K #	2
R508	915327	4.7K "	1
R509	915341	15K "	1
R510	915170	5.6K ·· 1/4 watt	1
R511	915053	2.7K "	1
R512	915052	33К "	1
	•	50 working voltage unless	
otherwise spe	ecified.		
C501, 502	913180	Electrolytic 47uF 16V	2
C503	913020	Mylar 0.01uF	1
C504	913180	Electrolytic 47uF 16V	1
C505	913349	Electrolytic 1uF (NP)	î
C506	913125	Ceramic 0.022uF	1
C507	913174	Electrolytic 100uF 25V	1
C508	913349	Electrolytic 1uF (NP)	1
C509	913071	Mylar 0.001uF	1
C510	913175	Electrolytic 10uF 16V	1
BR401	915519	Block Resistor 100K ohm x 10	1
(Keyboard)		MS10410	
BR402	915518	Block Resistor 100K ohm x 7	1
(")		MS1047	1

3. TUNER P.C. BOARD

Ref. No.	Part No.	Description	Q′ty
SEMI-COND	UCTORS 8	COILS	
Q1	916176	Silicon Transistor 2SC1070	1
02	916116	Silicon Transistor 2SC1674 or 2SC2786	T
Q3	916173	Silicon Transistor 2SC1730	1
Q4	916233	Silicon Transistor 3SK74 or 3SK41	٦
Q5	916116	Silicon Transistor 2SC1674	1
Q6	916233	Silicon Transistor 3SK74 or 3SK41	ĩ
Q7	916116	Silicon Transistor 2SC1674	1
D1	923395	Diode IS-2222	1
D2, 3, 4	923416	Diode IS-2209	3
D5, 6	923395	Diode IS-2222	2
D7	923416	Diode IS-2209	1
D8	923395	Diode (S-2222	1
D9, 10	923416	Diode IS-2209	2
D11 thru, 14	923395	Diode IS-2222	4
D15	923211	Diode ISV-50	1

Ref. No.	Part No.	Description	Qʻty
D16, 17	923395	Diode IS-2222	2
D18	923211	Diode JSV-50	1
D19	923147	Diode IS953	1
IFT1	922501	IFT 10741	1
L1	924020	Coil, UHF 1/2t	1
L2	923923	Coil, VHF MC108 5-1/2t	1
L3	924021	Coil, UHF 1/2t	1
L4	924022	Coil, UHF 1/2t	1
L5	913624	Micro Inductor 1uH	1
L6, 7	923922	Coil, VHF MC108 3-1/2t	2
L8	913216	Micro Inductor 2.2uH	1
L9	923922	Coil, VHF MC108 3-1/2t	1
L10	923923	Coil, VHF MC108 5-1/2t	1
∟11	923922	Coil, VHF MC108 3-1/2t	1
L12	923923	Coil, VHF MC108 5-1/2t	1
L13	913624	Micro Inductor JuH	1
∟14	923923	Coil, VHF MC108 5-1/2t	1
L15	923926	Coil, VHF MC116 5-1/2t	1
L16	923929	Coil, VHF MC116 9-1/2t	1

3. TUNER P.C. BOARD

Ref. No.	Part No.	Description	Q'ty	Ref. No.	Part No.	D	lescription	
L17	913572	Micro Inductor 4.7uH	1	R59	915003	1K ohn	7	
L18	923923	Coil, VHF MC108 5-1/2t	1		1	I		
L19	923926	Coil, VHF MC116 5-1/2t	1		RS, all are in	n 50 workin	g voltage u	inless
L20	923929	Coil, VHF MC116 9-1/2t	1	otherwise sp	pecified.			
L21	913624	Micro Inductor 1uH	1	C1	913051	Ceramic	0.001uF	
TC-1, 2, 3	913530	Trimmer Condenser 20pF 50	3	C2	913051	Ceramic	0.001uF	
10-1, 2, 3	913530	Truitmer Condenser 20pr 50		C2 C3	913051	Ceramic	0.001uF	
DESISTOR	Call are 1/9	watt 10% tolerance unless			913057			
otherwise sp		wall 1078 tolerance unless		C4 C5	1	Ceramic	2pF	
otherwise sp	ecified.		1		913132	Ceramic	2pF	(СП)
Rî	915015	10K ohm	1	C6	913051	Ceramic	0.001uF	
R2	915327	4.7K "	1	C7, 8	913060	Ceramic	0.01uF	10113
R3	915001	1.5K "	1	C9	913330	Ceramiic	6pF	
R4	915327	4.7K "	1	C10	913294	Ceramic	3pF	(CH)
R5	915052	33K "	1	C11	913629	Fixed	3pF	
R6	915351	330	1	C12	913060	Ceramic	0.01uF	
R7	915325	3.9K		C13	913063	Ceramic	0.047aF	
RS	915015	10K	1	C14	913060	Ceramic	0.01wF	
R9, 10	915052	33K -	2	C15	913171	Ceramic	30pF	
		6.8K "	1	C16	913060	Ceramic	0.01uF	
R11	915340			C17	913122	Ceramic	7pF	
R12	915057(J)	470	· · ·	C18	913060	Ceramic	0.01uF	
R13	915052	33K		C19	913051	Ceramic	0.001uF	
R14	915057(J)	470 "	1	C20	913053	Ceramic	5pF	
R15	915060	10 "	1	C21	913125	Ceramic	0.022uF	
R16, 17	915009	100 "	2	C22	913051	Ceramic	0.0014F	
R18	915015	10K "	1	C23	913060	Ceramic	0.01uF	
R19	915004	3.3K "	1	C24	913427	Ceramic	18pF	(CH)
R20	915342	22K "	1	C25	913052	Ceramic	10pF	
R21	915327	4.7K ~	1	C26	913051	Ceramic	0.001uF	
R22	915325	3.9K "	1	C27	913060	Ceramic	0.01uF	
R23	915007	2.2K ~	1	C28	913052	Ceramic	10pF	
R24	915340	6.8K "	1	C29, 30, 31	913060	Ceramic	0.010F	
R25	915039	100K "	1	C32	913427	Ceramic	18pF	0241
R26	915341	15K "	1	C33	913081	Ceramic	1pF	(Orti
R27	915052	33K ["]	1		1.500.00000000000		18pF	(CH)
R28	915039	100K "	1	C34	913427	Ceramic	0.01uF	icrit
R29	915336	220 "	1	C35	913060	Cerarmic		
R30	915015	10K "	1	C36	913078	Ceramic	4pF	
R31	915327	4.7K "	T	C37, 38, 39	923060	Ceramic	0.01uF	
R32	915001	1.5K "	1	C40	913076	Ceramic	2pF	
R33, 34	915039	100K "	2	C41	913125	Ceramic	0.022uF	
R35	915015	10K "	1	¢42	923078	Ceramic	4pF	
R36	915340	6.8K ~	1	C43	913052	Ceramic	10pF	
R37	915052	33K *	1	C44	913051	Ceramic	0.001uF	
R38	915009	100 "	1	C45	913625	Ceramic	0.001uF	(B)
R39	915057(J)	470	11	C46	913171	Ceramic	30pF	
			1	C47	913051	Ceramic	0.001uF	
R40	915015	10K "	1	C48, 49	913060	Ceramic	0.01uF	
R41	915339	1.8K "		C50	913051	Ceramie	0.001uF	
R42	915003	1K "	1	C51	913053	Ceramic	SpF	
R43	915039	100K "	1	C52	913060	Ceramic	0.01uF	
R44	915341	15K "	1	C53, 54	913125	Ceramic	0.022uF	
R45	915052	33K "	1	C55	913625	Ceramic	0.001uF	(8)
R46	915039	100K "	1	C56	913060	Geramic	0.01uF	2310
R47	915354	150 "	1	C57	913052	Ceramic	10pF	
R48	915336	220 "	1	C58	913077	Ceramic	220pF	
R49	915327	4.7K ··	1	C59	913075	Ceramic	4.7pF	
R50	915003	1K "	1	C60	813075	Ceramic	4.7pF	
R51	915039	100K "	1	C61, 62, 63	913060	Ceramic	0.01NF	
R52	915052	33K ~	1	C64, 65, 66	913125	Ceramic	0.022uF	
R53	915340	6.8K ·	1	C67	819169	No compo		
R54	915057(J)	470 ~	1	C68	913125	Ceramic	0.022u₣	
DCC	915009	100 "	1		913060	Ceramic	0.010F	
R55								
R56, 57	915003	1	2	C69	313000	Veranno	0.0101	

Q'ty

T

4. PLL P.C. BOARD

Ref, No.	Part No,	Description	Q'ty	Ref. No.	Part No.	Description	Q
SEMI-CONDU	CTORS 8	COIL		BR107	915591	Block Resistor MS1034	
C101	916218	IC MC3357P	1	VR101	915594	Slide Volume 5K (B), SQ	
C102	916221	IC LA1201	1	VB102	915595	Solid Volume 22K (B)	
C103	916223	IC SO42P	1	VR103	915581	Stide Volume 20K (A),	
C104	916219	1C SP8629	1	• mros	313301	VOLUME	
			· ·	VD104	015500		
C105	916225	IC uPD2819C		VR104	915580	Slide Volume 20K (B),	
C106	916185	JC uPB551C	1	12		Fine Tuning	
C107	916182	IC SN74LS162N	1	VR105	915596	Solid Volume 47K	1
C108	916229	IC uPD4015C	1		0000.00		
C109	916228	IC uPD4011C	1	X1	923945	Crystal Unit 10.245 MHz	
C110	916238	IC SN74LS107AN	1	X2	923943	Crystal Unit 5.76 MHz	
C111	916184	IC SN74LS00N	1	×3	923944	Crystal Unit 7,20 MHz	
2112	916227	IC uPD5101LC	1	×4	923942	Crystal Unit 4.80 MHz	
C113	916198	IC uPA53C	1	×5	923943	Crystal Unit 5.76 MHz	
2114	916225	IC uPD2819C	1				1
C115	916224	IC uPD553C	1	RESISTORS	all are 1/8	watt 10% tolerance unless	
				otherwise spe			
2116	916239	IC uPC2002	1	Chief Wide ape	1 1		1
2117	916241	IC 78MO8 AVR	1	B101	915015	10K ohm	
0118	916240	IC 78MO5 AVR	1	R102	915343	10/1 "	
101 thru, 104	916158	Silicon Transistor 2SC945L	4	R102	915007	2.2K "	
				202			
105 thru. 111	916116	Silicon Transistor 2SC1674	7	R104	915427	82K "	
112	916194	Silicon Transistor 2SA733	1	R105	915343	47K "	
113	916158	Silicon Transistor 2SC945L	1	R106	915372	56K "	
114	916116	Silicon Transistor 2SC1674	1	R107	915327	4.7K "	
115, 116, 117	916158	Silicon Transistor 2SC945L	3	R108	915427	82K ~	
118	916194	Silicon Transistor 2SA733	1	R109	915327	4.7K "	
	000447	2010		R110	915342	22K "	
101, 102	923147	Diode IS953	2	8111	915337	680 "	
103, 104	922604	Diode IS188	2	R112	915473	820K "	
105, 106		No component		R113	915340	6.8K "	
107	923211	Diode ISV-50, Varactor	1		10.000		-
108, 109	923147	Diode IS953	2	R114	91537:2	56K "	
110	923588	Diode RD6.2EB, Zener	1	R115	915001	1.5K "	
111, 112	923147	Diode 15953	2	R116	915007	2.2K "	
113	923793	Diode RD5.6EB, Zener	1	R117	915039	100K "	
114 thru. 121	923147	Diode IS953	8	R118	915003	1K "	
			87.1	R119	915039	100K «	
122	924009	Diode RD18EB, Zener	1	R120	915327	4.7K "	
123, 124, 125	923395	Diode IS2222	3	R121	915343	47K "	
126	923211	Diode ISV-50, Varactor	1	B122	915007	2.2K "	
127	923147	Diode IS953	1	R123			
128	923588	Diode RD6.2EB, Zener	1		915003	1K "	
129	923817	Diode SR1K-2	11	R124, 125	915001	1.5K "	
130, 131	923147	Diode IS953	2	R126	915354	150 "	1
100,101	020147	BRADE (2000		R127	915198	47 "	- T
101	913624	Micro Inductor JuH	1	R128	915337	680 "	
102	913627	Coil L-156B R-12NNO419	1	R129	915003	1K "	1
103	913624	Micro Inductor 1uH	1	R130	915055	8.2K "	
104, 105, 106	913630	Micro Inductor 10uH	3	R131	915015	10K "	
107, 108	914020	Filter Choke	2	R132, 133	915327	4.7K "	
107, 100	314020		-				
H101	914028	Choke Coil 4028	1	R134	915047	820 "	
T404 105				R135	915356	68 "	
T101, 102	92283B	IFT M402 353N	2	R136	915015	10K "	
F1, 2	924026	Crystal Filter 10.7MHZ	2	R137	915004	3.3K "	
., -	02.1020	aryona inter to mina		R138	915336	220 "	
F101	923555	Ceramic Filter CFW455D	1	R139	915366	33 "	1
F102	924007	Ceramic Filter CFW455G	1	R140	915057	470 "	
	1		_	B141	915052	33K "	
C101 thru. 105	913519	Trimmer Condenser 50pF 70	5	R142	915337	680 "	
R101	915592	Block Resinor MS6824	1				
			1	R143	915336	220 "	
R102	915586	Block Resistor MS6824C		R144	915343	47K "	
R103	915590	Block Resistor MS4734	1	R145	915052	33K "	
R104	915518	Block Resistor MS1047	1	R146	915003	1K "	
C 20E	915588	Block Resistor DIP1047	1	R147, 148	915340	6.8K "	
R105							

4. PLL P.C. BOARD

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Ref, No.	Part No.	De	scription	Q'ty	Ref. No.	Part No.	Description		Q
R150	915340	6.8K ohm		1	C105, 106	913107	Ceramic 250pF		2
R151	915001	1.5K "		1	C107	913452	Ceramic 50pF	(SH)	1
R152, 153	915015	10K "		2	C108	913060	Ceramic 0.01uF		1
R154	915336	220 "		1	C109	913021	Mylar 0.1uF		1
R155	915367	470K "		1	C110	913151	Ceramic 10pF	(SH)	1
R156 thru, 160	915015	10K "		5	C111	913060	Ceramic 0.01uF	(311)	1
R161, 162, 163	915004	3,3K "		3		1000			
					C112	913021	Mylar 0.1uF		1
R164	915015	10K "		1	C113, 114	913060	Ceramic 0.01uF		2
R165	915057	470 "		1	C115	913021	Mylar 0.1uF		1
R166	915052	33K "		1	C116	913180	Electrolytic 47uF	16V	1
R167	915342	2 2 K "		1	C117	913175	Electrolytic 10uF	16V	1
R168	91503 9	100K "		1	C118	913148	Electrolytic 4.7uF	16V	1
R169	915057	470 "		1	C119	913125	Ceramic 0.022uF		1
R170	915368	68K "		1	C120, 121	913020	Mylar 0.01uF	1	2
R171	915003	1K "		1	C122	913452	Ceramic 50pF	(SH)	1
8172	915052	33К ~		1	C123	913063	Ceramic 0.047uF		1
R173	915009	100 "		il	C124	913631	Ceramic 0.001uF		1
174	915342	22K "		l i l	C125	913020	Mylar 0.01uF		î
175	915009	100 "		1	C125	913060	Ceramic 0.01uF		1
176	915351	330 "		1		913148		161/	1
177	2.5				C127		Electrolytic 4.7uF		
178	915340 915007	6.8K ~ 2.2K ~			C128	913175	Electrolytic 100F	100	1
				1	C129	913060	Ceramic 0.01uF		1
179	915340	6.8K "		1	C130	913078	Ceramic 4pF	1	1
180	915354	150 ~		1	C131	913125	Ceramic 0.022uF		1
181, 182	915342	22K "		2	C132	913060	Ceramic 0.01uF	1	
183, 184	915386	1M "		2	C133	913266	Ceramic 82pF		
185 thru, 189	915039	100K "		5	C134	913125	Ceramic 0.022uF		
190 thru. 194	915343	47K "		5	C135	913060	Ceramic 0.01uF		
195	915053	2.7K "		1 1	C136	913051	Ceramic 0.001uF		
196, 197, 198	915015	10K "		3	C137	913060	Ceramic 0.01uF		1
199	915367	470K ~		1		513000			
	10.1				C138		No component	ļ	
3200	915412	150K "		1	C139, 140	913051	Ceramic 0.001uF		2
31201	915015	10K "		1	C141	913060	Ceramic 0.01uF		ĵ
R1202	915573	10M "		1	C142, 143	913125	Ceramic 0.022uF	1	2
31203	915055	8.2K "			C144	913060	Ceramic 0.01uF	1	1
(1)35-2(23)	100000000000000000000000000000000000000			1	C145	913125	Ceramic 0.022uF		1
1204, 1205,	915342	22K "		3	C146	913051	Ceramic 0.001uF		1
1206	23333223				C147	913151	Ceramic 10pF	(SH)	1
R1207	915015	10K "		1	C148	913482	Ceramic 30pF		7
R1208	915342	22K "		1		913376	Ceramic 50pF	1	1
R1209	915015	10K "		1	C149	0210100000000000			
1210	915343	47K "		1	C150	913115	Ceramic 120pF	(1) (2)	1
1211	915039	109K "		1	C151	913348	Electrolytic 0.47uF	(NP)	1
1212	915327	4.7K "		1	C152, 153	913077	Ceramic 220pF	1	2
1213	915336	220 "	1/2 watt	1	C154	913097	Electrolytic 100uF	16V	1
1214		2.2K "	1/2 Wall	1 I	C155	913082	Ceramic 50pF	(UJ)	1
1	915007		1/2		C156	913072	Ceramic 22pF	(UJ)	1
1215, 1216	915091	10 "	1/2 watt	2	C157 thru. 161	913436	Tantalum 0.47uF		5
1217	915051	68 "	**	1	C162	913331	Semi-Con. 0.1uF		1
1218	915007	2.2K "		1	C163	913276		(CH)	1
1219	915360	270 "		1	C164, 165	913051	Ceramic 0.001uF		-
1220	915007	2.2K -		1		913060	Ceramic 0.001uF		1
1221	915523	1 "		1	C166	2010/00/00/00/00		161/	
1222	915015	10K "		1	C167	913097	Electrolytic 100uF		1
1223	915003	1K "		1	C168	913062	Electrolytic 470uF		1
1224	915327			1	C169, 170	913174	Electrolytic 100uF		2
1225	915395	27K "		1	C171	913097	Electrolytic 100uF	16V	1
1226	915039	100K "		1	C172	913125	Ceramic 0.022uF		ĵ
	10000	TOOK .			C173	913626	Tantalum 10uF	16V	1
ADACITODO	all are in	E0 washin -			C174	913331	Semi-Con. 0.1uF		1
APACITORS,		on working (voitage uniess		C175, 176	913482	Ceramic 30pF	(SH)	2
therwise specif	led.				C177	913461	Čeramic 2pF		1
101	913148	Electrolytic	4.7uF 16V	11		913051	Ceramic 0.001uF		1
2	-			1	C178				
102	913175	Electrolytic	10uF 16V		C179	913125	Ceramic 0.022uF	1011	1
2103	913627	Tantalum	0.22uF 16V	1 1	C180	913626	Tantalum fOuF	16V	1
:104	913021	Mytar	0,1uF		C181		Film Con. 0.:33uF		1

4. PLL P.C. BOARD

Ref. No.	Part No.	Description	Q'ty	Ref. No.	Part No.	Description	Q'ty
C182	913348	Electrolytic 0.47uF	1	C1206, 1207	923480	Tantalum 33uF 16V	2
C183	913030	Electrolytic 470uF 16V	1	C1208	913594	Electrolytic 1uF (NP)	1
C184	913061	Electrolytic 1000uF 16V	1	C1209 thru.	913125	Ceramic 0.0220F	5
C185	913030	Electrolytic 470uF 16V	1	1213			
C186	913069	Electrolytic 220uF 16V	1	C1214	913480	Tantalum 33uF 16V	1
C187, 188	913030	Electrolytic 470uF 16V	2	C1215	913060	Ceramic 0.01uF	1
C189	913069	Electrolytic 220uF 16V	1	C1216, 1217,	913125	Ceramic 0.022uF	3
C190	913592	Electrolytic 0.22uF (NP)	1	1218			
C191	913021	Mylar 0.1uF	1	C1219	913069	Electrolytic 220uF 16V	1
C192	913069	Electrolytic 2200F 16V	1	C1220, 1221,	913125	Ceramic 0.022vF	3
C193, 194, 195	913435	Tantalum 0.33uF 16V	3	1222			
C196 thru, 199	913060	Ceramic 0.01uF	4	C1223, 1224	913051	Ceramic 0.001uF	2
C1200	913125	Ceramic 0.022uF	1	C1225, 1226	913060	Ceramic 0.01uF	2
C1201	913060	Ceramic 0.01uF		C1227	913125	Ceramic 0.022uF	1
C1202	913183	Ceramic 68pF					
C1203, 1204 , 1205	913060	Ceramic 0.01uF	3				

5. VCO P.C. BOARD

Ref, No.	Part No.	Description	Q'ty	Ref. No.	Part No.		Description	Q'ty
SEMI-CONE	DUCTORS 8	COILS		R310	915015	10K	ohm	1
	1			R310	915340	6.8K		1
Q201 thru.	916116	Silicon Transistor 2SC1674	5	R312	915342	22K	"	1
205		1210		R313	915003	ıк		1
Q206	1000000000	No component		R314	915015	1 10K	"	1
Q207 thru.	916116	Silicon Transistor 2SC1674	4	R315	915340	6.8K	"	1
210			225	B 316	915342	22K		1
Q211	916158	Silicon Transistor 2SC945L	1	R317	915003	1K		1
Q212 thru.	916194	Silicon Transistor 2SA733	4	B318	915015	10K		1
215				R319	915340	6.8k	**	1
Q216	916158	Silicon Transistor 2SC945L	1	R320	915409	5.6K		1
Q217, 218	916194	Silicon Transistor 2SA733	2	8321 thru.	915015	10K	**	8
0201	923211	Diode ISV-50, Varactor	1	328	0.00.0	1011		
D202, 203	923416		2	B329 thru,	915342	22K	"	4
D202, 203 D204 thru.	923395	Diode IS-2209, " Diode IS-2222	4	332	0,0012	221		
207 mru.	923395	Luode 13-2222	4	R333	915007	2.2K		1
	000011			8334	915015	10K	"	1
D208, 209,	923211	Diode ISV-50, Varactor	3	R335	915340	6.8K		1
210	000117			R336, 337	915343	47K		2
D211 thru.	923147	Diode 19953	5	R338	915007	2.2K		1
215				R339	915410	560		i
L201, 202	923930	Coil MC108 2-1/2t	2	R340	915342	22K		1
L203	923922	Coil " 3-1/2t	1	R341		100		i i
L204	923926	Coll MC116 5-1/2t	il		915009			1
L205	923927	Cail - 6-1/2t	i	R342	915057(J)	470	14	
L206	923928	Coil " 8-1/2t	1	R343	915052	33K		9.2
L200	.92.0920	GOIL 0-1721	1	R344	915009	100	"	1
TC201 thru.	913529	Trimmer Condenser 10pF 50	6	R345	915342	22K	•1	1
206				R346	915344	220K	0	1
	1	1		R347	915003	1K	12	1
RESISTORS	S, all are 1/8	watt 10% tolerance unless		R348	915015	10K	"	1
otherwise sp	ecified.			R349	915003	10K	"	1
-				R350	915015	10K	"	1
R301	915057(J)	470 ohm	1	R351	915003	tκ		1
R302	915009	100 "	1	R352	915015	10K	"	1
R303	915052	33K "	1	R353	915010	10	" 1/4 watt	11
R304, 305	915009	100 "	2	R354	915003	١ĸ	"	1
R306	915337	680 "	1	R355	915015	10K		1
R307	915343	47K "	1	R356	915003	1K	"	1
R 308	915342	22K "	1	R357	915015	10K	"	1
R309	915410	560 "	1	R358	915342	22K	"	2

5. VCO P.C. BOARD

Ref. No.	Part No.	Description	Q'ty	Ref. No.	Part No.	Des	cription
CAPACITOR otherwise sp		50 working voltage unless		C325, 326, 327	913060	Ceramic	0.01uF
C301, 302 C303 C304 C305 C306 C307 C308 C309 C310 C311 C312 C313 C314 C315 C316 C317 C318, 319 C320 C321 C322 C323 C324	913060 913268 913076 913265 913081 913172 913122 913063 913122 913051 913060 913081 913060 913078 913060 913078 913060 913078 913060 913078 913060 913078	Ceramic0.01uFCeramic47pFCeramic2pFCeramic1pFCeramic1pFCeramic39pFCeramic7pFCeramic0.047uFCeramic0.01uFCeramic0.01uFCeramic1pFCeramic4pFCeramic4pFCeramic0.01uFCeramic4pFCeramic1pFCeramic4pFCeramic1pFCeramic1pFCeramic4pFCeramic4pFCeramic4pFCeramic4pFCeramic4pFCeramic0.01uFCeramic4pFCeramic4pFCeramic0.01uFCeramic4pFCeramic0.01uFCeramic4pFCeramic4pFCeramic4pF	2 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	C328 C329 C330 C331 C332 thru. 337 C338 C339 thru. 343 C344 C345 C344 C345 C346 C347, 348 C349 C350 C351 C352 thru. 357 C358 C359 C360 thru. 363	913093 913078 913336 913093 913060 913125 913060 913076 913076 913076 913076 913076 913081 913060 913080 913060 913069 913069	Ceramic Ceramic Electrolytic Ceramic	25pF 4pF 4.7uF 25V 25pF 0.01uF 0.01uF 15pF 2pF 30pF 0.01uF 15pF 0.01uF 15pF 0.01uF 15pF 0.01uF 15pF 0.01uF

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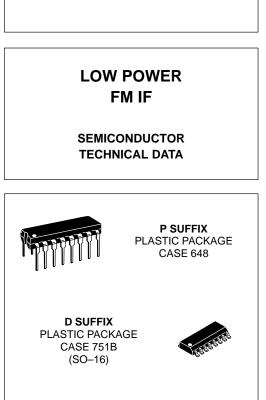




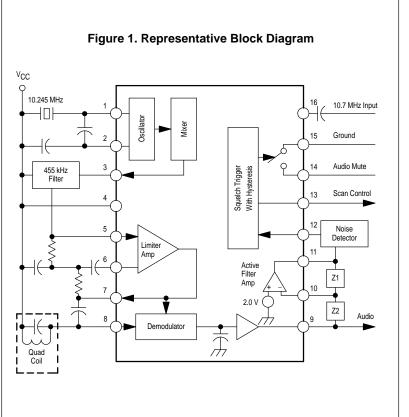
Low Power Narrowband FM IF

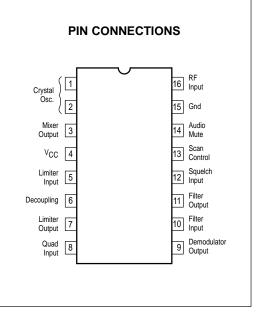
... includes Oscillator, Mixer, Limiting Amplifier, Quadrature Discriminator, Active Filter, Squelch, Scan Control, and Mute Switch. The MC3357 is designed for use in FM dual conversion communications equipment.

- Low Drain Current (3.0 mA (Typical) @ V_{CC} = 6.0 Vdc)
- Excellent Sensitivity: Input Limiting Voltage (- 3.0 dB) = 5.0 μV (Typical)
- Low Number of External Parts Required
- Recommend MC3372 for Replacement/Upgrade



MC3357





ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC3357D	T _A = − 30 to +70°C	SO-16
MC3357P	$I_{A} = -3010 + 70 C$	Plastic DIP

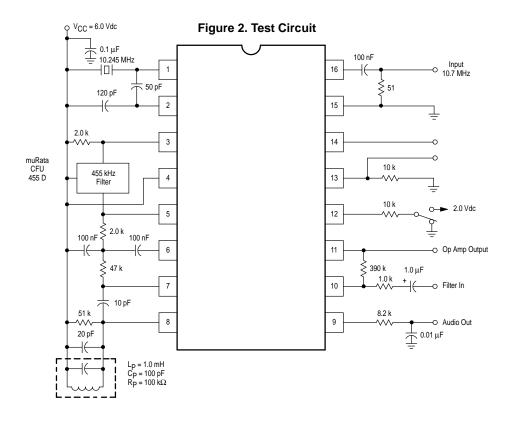
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MAXIMUM RATINGS (T_A = 25° C, unless otherwise noted)

Rating	Pin	Symbol	Value	Unit
Power Supply Voltage	4	V _{CC} (max)	12	Vdc
Operating Supply Voltage Range	4	VCC	4 to 8	Vdc
Detector Input Voltage	8	-	1.0	Vp–p
Input Voltage ($V_{CC} \ge 6.0$ Volts)	16	V ₁₆	1.0	V _{RMS}
Mute Function	14	V ₁₄	-0.5 to 5.0	Vpk
Junction Temperature	-	Тj	150	°C
Operating Ambient Temperature Range	-	TA	- 30 to + 70	°C
Storage Temperature Range	-	T _{stg}	– 65 to + 150	°C

$\textbf{ELECTRICAL CHARACTERISTICS} (V_{CC} = 6.0 \text{ Vdc}, \text{ fo} = 10.7 \text{ MHz}, \Delta f = \pm 3.0 \text{ kHz}, \text{ f}_{mod} = 1.0 \text{ kHz}, \text{ T}_{A} = 25^{\circ}\text{C}, \text{ unless otherwise noted.})$

Characteristic	Pin	Min	Тур	Max	Unit
Drain Current Squelch Off Squelch On	4		2.0 3.0	- 5.0	mA
Input Limiting Voltage (- 3 dB Limiting)	16	_	5.0	10	μV
Detector Output Voltage	9	-	3.0	-	Vdc
Detector Output Impedance	-	-	400	-	Ω
Recovered Audio Output Voltage (Vin = 10 mV)	9	200	350	-	mVrms
Filter Gain (10 kHz) (V _{in} = 5 mV)	-	40	46	-	dB
Filter Output Voltage	11	1.8	2.0	2.5	Vdc
Trigger Hysteresis	-	-	100	-	mV
Mute Function Low	14	-	15	50	Ω
Mute Function High	14	1.0	10	-	MΩ
Scan Function Low (Mute Off) (V ₁₂ = 2 Vdc)	13	-	0	0.5	Vdc
Scan Function High (Mute On) (V ₁₂ = Gnd)	13	5.0	-	-	Vdc
Mixer Conversion Gain	3	-	20	-	dB
Mixer Input Resistance	16	-	3.3	-	kΩ
Mixer Input Capacitance	16	-	2.2	-	pF



CIRCUIT DESCRIPTION

The MC3357 is a low power FM IF circuit designed primarily for use in voice communication scanning receivers.

The mixer–oscillator combination converts the input frequency (e.g., 10.7 MHz) down to 455 kHz, where, after external bandpass filtering, most of the amplification is done. The audio is recovered using a conventional quadrature FM detector. The absence of an input signal is indicated by the presence of noise above the desired audio frequencies. This "noise band" is monitored by an active filter and a detector. A squelch trigger circuit indicates the presence of a noise (or a tone) by an output which can be used to control scanning. At the same time, an internal switch is operated which can be used to mute the audio.

The oscillator is an internally–biased Colpitts type with the collector, base, and emitter connections at Pins 4, 1, and 2 respectively. A crystal can be used in place of the usual coil.

The mixer is doubly–balanced to reduce spurious responses. The input impedance at Pin 16 is set by a 3.0 k Ω internal biasing resistor and has low capacitance, allowing the circuit to be preceded by a crystal filter. The collector output at Pin 3 must be dc connected to B +, below which it can swing 0.5 V.

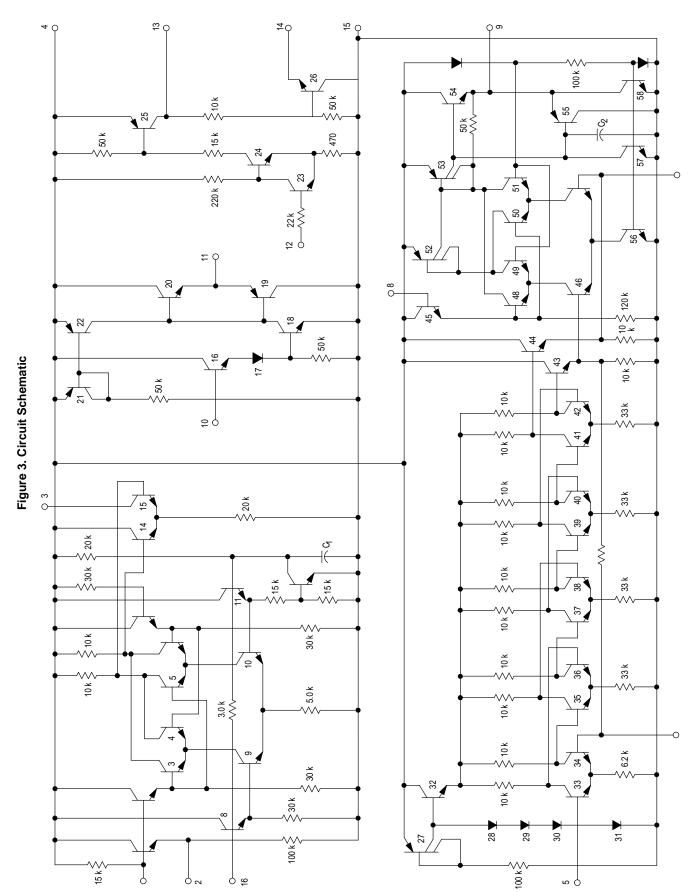
After suitable bandpass filtering (ceramic or LC), the signal goes to the input of a five-stage limiter at Pin 5. The output of the limiter at Pin 7 drives a multiplier, both internally directly,

and externally through a quadrature coil, to detect the FM. The output at Pin 7 is also used to supply dc feedback to Pin 5. The other side of the first limiter stage is decoupled at Pin 6.

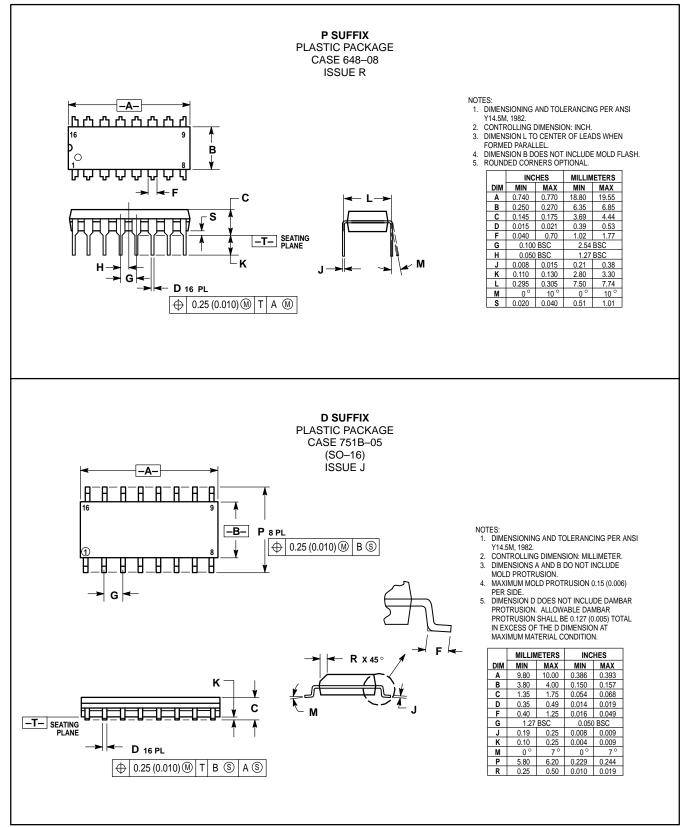
The recovered audio is partially filtered, then buffered, giving an impedance of around 400 Ω at Pin 9. The signal still requires de–emphasis, volume control and further amplification before driving a loudspeaker.

A simple inverting op amp is provided with an output at Pin 11 providing dc bias (externally) to the input at Pin 10 which is referred internally to 2.0 V. A filter can be made with external impedance elements to discriminate between frequencies. With an external AM detector, the filtered audio signal can be checked for the presence of noise above the normal audio band, or a tone signal. This information is applied to Pin 12.

An external positive bias to Pin 12 sets up the squelch trigger circuit such that Pin 13 is low at an impedance level of around 60 k Ω , and the audio mute (Pin 14) is open circuit. If Pin 12 is pulled down to 0.7 V by the noise or tone detector, Pin 13 will rise to approximately 0.5 Vdc below supply where it can support a load current of around 500 μ A and Pin 14 is internally short–circuited to ground. There is 100 mV of hysteresis at Pin 12 to prevent jitter. Audio muting is accomplished by connecting Pin 14 to a high–impedance ground–reference point in the audio path between Pin 9 and the audio amplifier.



OUTLINE DIMENSIONS



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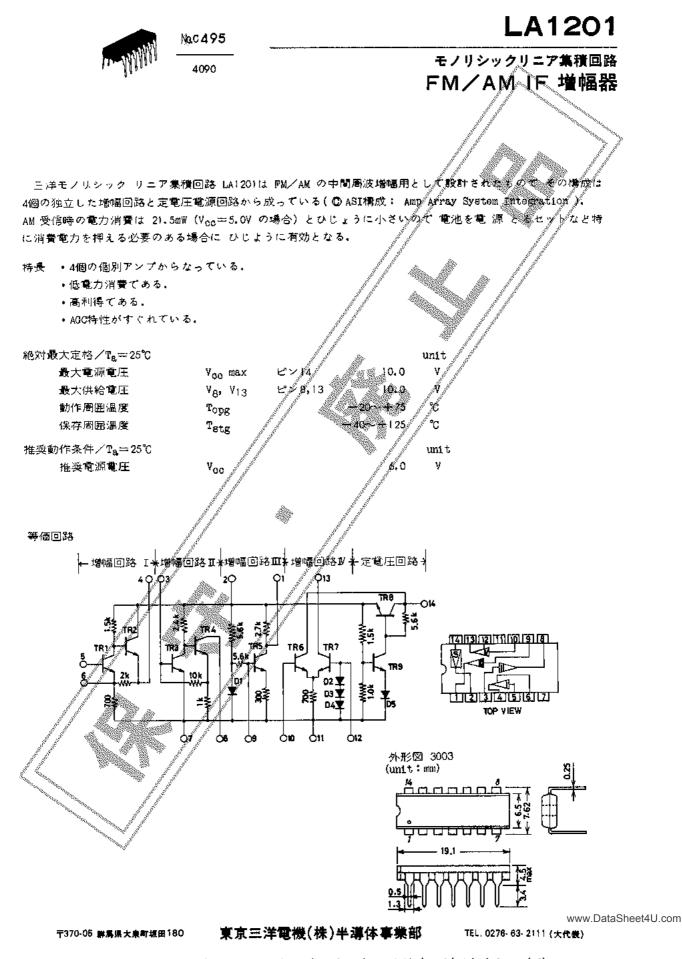
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4090YO新N/8057YO色カ/6133修1k k1/0112(2213)k1/D010十付/N009(16A)/N258k1(12) N0.495-1/10 www.DataSheet4U.com

動作特性ノ	′Ta=25℃,	指定測定回路において、	Vcc=5.0V
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項目	記号	条件	MA	(45 5 kH2	5)	<u></u>	(10.70	lz)	単位
-7, C	<u>م</u> مه	* 1	min	typ	Dax	min	typ	Bax	-42- <u>117</u>
無信号電流	Icco		2.7	4.2	6.3	4,5	6.8	2.0	шA
AM 検波出力	Vo	入力 60dB	70	115	160		and the second second	Sugar Carrier	N 947
全高調波ひずみ率	THDI	入力 60dB		0.8	2.0	all the second	a state of the sta		30
大入力ひずみ率	THD2	入力 80dB		1.8	3.0	AND THE OWNER OF THE OWNER		alh. I	%
差動対電流	II3	ピン13			and the second second	Ø. 75	1.0	1. 35	,∎A,∕
定電圧出力	٧2	ビン2	2, 7	3.0	3.3	2.7	3.0	3.3	and the second sec
	VQ	入力 AM:20dB,FM:50dB	70	j.	87	82	100	×8/	dB

(注)総合利得※: LA1201 が高利得 IC のため FM の利得の測定は、段間で利得を 40 gB 程度押えた
回路(pl0参照)で、検波出力値を 14V=0 gB として示してあり、実際の 応用回路における場合と相関が取れるようになっている・応用例を参照したい。

なお AM については実際の応用回路と同一の回路で測定している。

[参考] 各段ごとの利得配分,あるいはセラミックフィルタ使用時のように 抵抗負荷 で使用する場合の利得については次の値を参照したい.

and the second se	增幅回路 【增幅回路工	增幅回路田	增幅回路政	単位
AM (455kHz)	30 35	-14	-	₫₿
FM (10.7MHz)	25 30	_	20	đB

増幅回路 葉,並の RL=lkΩ とする.

LA1201 の構成

• 增幅回路 I(可変利得段; MC)

・増幅回路 至(固定利得段)

固定利得段で、原路構成は典型的な黄帰還回路であるため 温度特性は良好でパラツキ の少ない安定な利得が得られる。 増幅回路Iのエミッタフオロワによる 低出カインピ ーダンスと合わせて回路IIの入力インピーダンスが低いため外乱による影響が少なくな る 出力端子ピン 8 は FM RP への必要な AGC 電圧にしたがって 定電圧 端子 ピ ング、または電源供給端子ピン14に接続する。

・増唱回路皿(融検波段)

/ M 検波増幅段で,ここではトランジスタ検波を採用しているため微少入力でも ひず みが少なく,また AGC ループゲインが大きく取れ,良好な AGC 特性が得られる。 増 幅回路 I の回路の AGC 特性とあいまって 2 段に AGC をかけたのと同等の AGC特性が 得られる。 またエミッタに局部帰還をかけてひずみ率の向上を図っている。 整合の とれたダイオード接続のトランジスタをパイアス回路に用いることによって、湿度特性 を向上させながらバラツキも防いている。 コレクタの直流レベル変化を直接用いて チュニングインジケータを付加することも可能である(応用技術資料的5参照)。

・増幅回路IV (FM リミタ・増幅段)

差動増幅のリミタアンプで構成され、この段は整合したトランジスタ対によって ImA ずつ均等に流れる。 身荷インピーダンスを Voo に応じで適当に遵ぶことにより 電流 リミタがかかり、リミタアンプとしてすぐれた特性が得られる。 またマース端子ビン 12 の電位を適当なスイッチング回路を用いて下けることにより、すぐれたミューティ ング特性が得られる。

・定電圧回路

帰還型の安定化電源で、入力電圧の変動に対しても消費電流はあまり変化セポ安定な 出力電圧が得られる。 増幅回路 I〜DUはすべてこの安定化電源によって 4.0〜9.0 V の間ではほとんどその特性は変らず、 10 dB 低下点は 3.5 V になっている。 また 定電圧出力端子 ピン 2 を FM チューナ、FM コンパータに利用する(最大 3mA まで可) と、それぞれ安定な性能を得られるように設計できる・

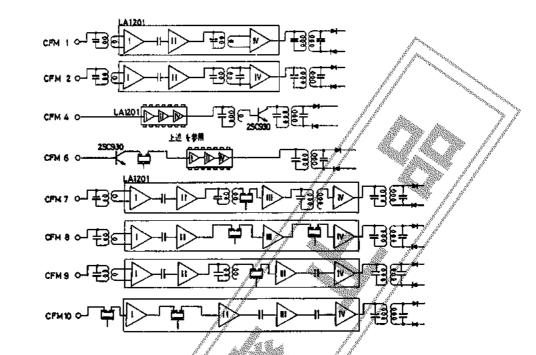
使用上の注意事項

- (1) 波形観測や電圧チェックの際、傾って端子 3~4 間, 端子 2~3 間を短絡すると、過大電流が流れ 破壊に至ることがあるので注意したい・
- (2) 端子 8, 13, 14 間には直路動作的に素 10 V 以上ががらないように設計する。
- (3) 増幅回路 I のバイアズ調整は、端子 4 と端子 8 間の電圧 V4-6 が無信号時に 0.5 V になるよう に調整、設定する。
 この場合内部抵抗が 50 kΩ 以上の直流電圧計を使用する。
 また FM または AM のいずれかの利得が最大になるように調整、設定することもできる。
 この場合の入力信号レベルは 数波出力 IQ mV 程度が適当である。
- (4) 笛音妨害を少なくするためには、フェライト パー アンテナ の軸方向を LA1201 の長軸方向と 直 角になるように配置する。 また局部発振電圧の IP 段への漏れにも注意したい。
- (5) 持て3Vくらいの低電源電圧式使用するときは、 端子2と14を短絡して電源供給端子とし 、使用する・ この場合 定電圧回路は動作しませんが減電圧特性以外は同じ特性が得られる・

LA/201 を応用した 証 増幅段の基本回路構成

(1) AM IF 段の構成例

AM 検波出力

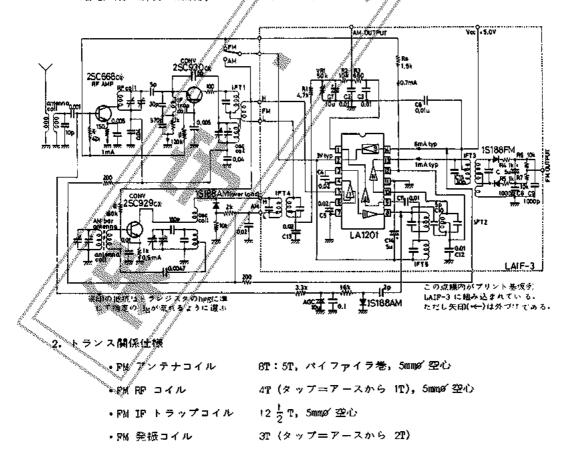


(2) FM TF 段の構成例 (TFT をセラミックフィルタに変更しただけのものは省いた).

応用例1、FM/AM ラジオ高周波回路

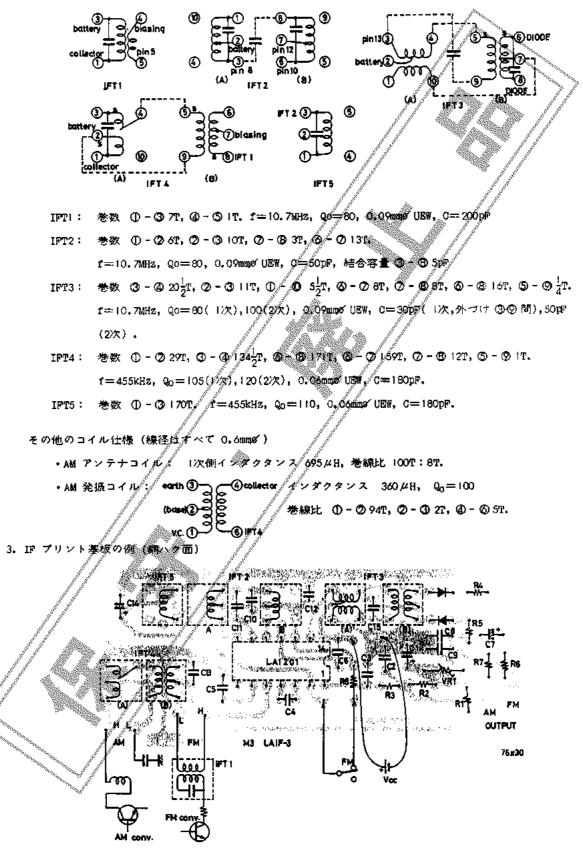
Ⅰ. 回路図: CFM-2

FM IF 段に前項の構成例の CFM 2, AM IF 段に CAM-1 て構成した例を示す。



・IFT の仕様

この回路に使用される IFT の仕様を示す。 IFTは すべて 7mm角である.

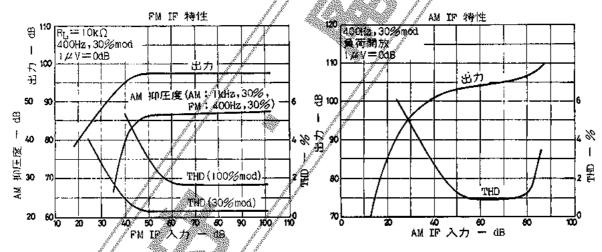


前ページのプリント基板図は IF プリントバターン設計の参考にしたい。 なお この基板図は IF部だけで FM /AM チューナ部分は含まれていない。

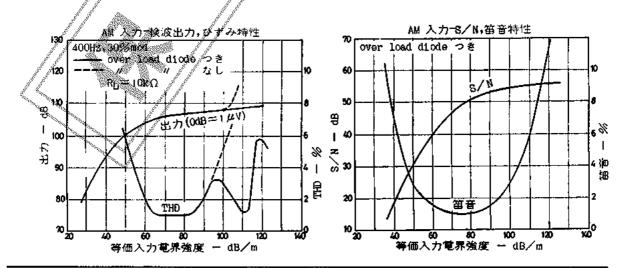
- [調整法] VRI 50kΩは 無信号時に V4-6 (すなわち ④ ⑥ 間の直流電圧) =0.5V になるように調整設定す るか または FM あるいは AMの利得が最大になるように調整,設定する・ このどぎ 局部発振電圧の IF段への漏れに注意したい・ この漏れによってAMパンド内での利得差や 笛音等が悪化することが ある・
- 4. IF 部分の電気的特性

前項 3.のプリントパターン例 LAIF-3は I. 回路図の点線内に相当する。 このプリントパターンズ/IF 部分のみの特性をチェックする場合は FM H-L間に 50Ω, AM L-アーズ間に 0.02μFを付加する。 この回路は LA1201 の特性を生かすため 次の点に考慮を払っている。

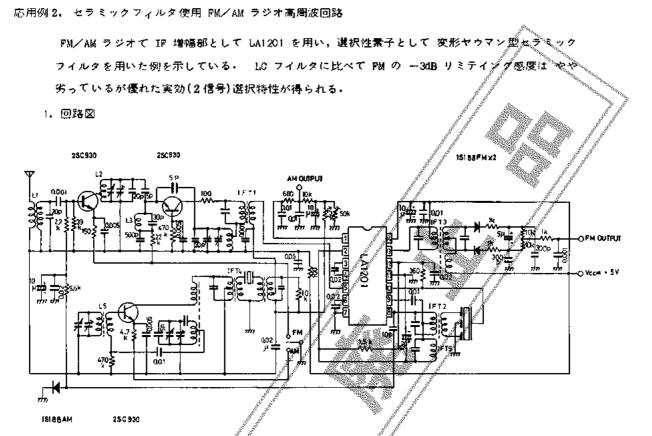
- (1) A M 受信時に R8(1.5kΩ)を切り離して 増幅回路 IV をガットオフにし 電流測量の低減を図っている-
- (2) 定電圧出力 V2をチューナ部のペースバイアスに用い 電流変動に対する変定化を図っている。
- (3) 笛音妨害を少なくするために AM フェライト イ アンテナは LA1201と運動になるように配置し そのうえて フェライト コアの位置を検討する・



- 5. セットに応用した場合の総合特性
 - (1) AM 特定/検波出力 10mV(R_L=」(成 Ω) を基準出力とする・[OdB=1μV]



・感度				
	圕波数	最大感度	実用感度	
	600 kHz	26 dB∕m	43.5 dB/m	in the second
	1000 kHz	26 dB∕m	44.5 dB/m	All and a second and a second and a
	1400 kHz	27 dB/m	44•5 dB∕m,//	A REAL PROPERTY AND A DESCRIPTION OF A D
• 選択度			Sector Sector	College College College
	1000 kHz_10 1	(Hz 23 dB (Hz 24 dB		r 17
(2)FM 特性 / 検	波出力 10mV(R」=10	<Ω)を基準出力とする	з. о ав≓∕1µV	\$\$#
• 感度			- // - &C.	\$1/
	周波数 最大感度	[実用感度 −3d	IBリミチイング感度 IHFM実施	h <u>®</u> ¢
	76 MHz −1 di	B 3⊾5 ⊄B	///3 dB 23 d	B
	83 I	4.0	/ 1 2 20	
	90 0	3.0	10 21	č.
•3 dB 帯城幅	200 kHz	and a start of the		
• 検波出力	60 mV			
・ひずみ率	0.4 % /入力	7 60 dB, 400 Hz, 22.5	5 kHz dev.	
	1.4 % / "	60 4B, 400 Hz, 75 1	Hz dev.	
		11 9222	** //	
	ي. بو	17 - 4.53,833	Ø //	
	and the second	1		
	AND			
「泰妥]中上の応囲砌	に掲げた 取取の時入(こついては 下記メータ	/	
	x 8	S. 3	-1279 電話 03-607-51	П
	J .H	18 A	2-1-17 電話 03-727-11	
IFT B		—————————————————————————————————————	東光コイル	
I	rrî		3725BM2	
b.	F/12 (A∕B) 75F01	(∰ ∕7\$ ₽02 85a0-∹	3726PAB2/85AC-3727SCP2	
Jan Stranger	(緑) FT3 (永子号)) 78F03			
and the second se	(#K)			
⊥ ************************************	F(fa(A/B)) = 7SAO(A)	/ ² 7SA02 LMC-50 (青) (岸	054PAR2/LMC-5055SLQ2 引) (線)	
I Manual I	FT5 (* 🚿 🔨 75403	LWC-50 (植	053HM2 2)	
	Start Start			
// ss.	and the second			
// #???	and the second second			
- // 88	8 //			
-// \\.?\`	. John Starter			
~~ ** *,				
	, ^e			
	A start and a start and a start a star			



2. 総合特性

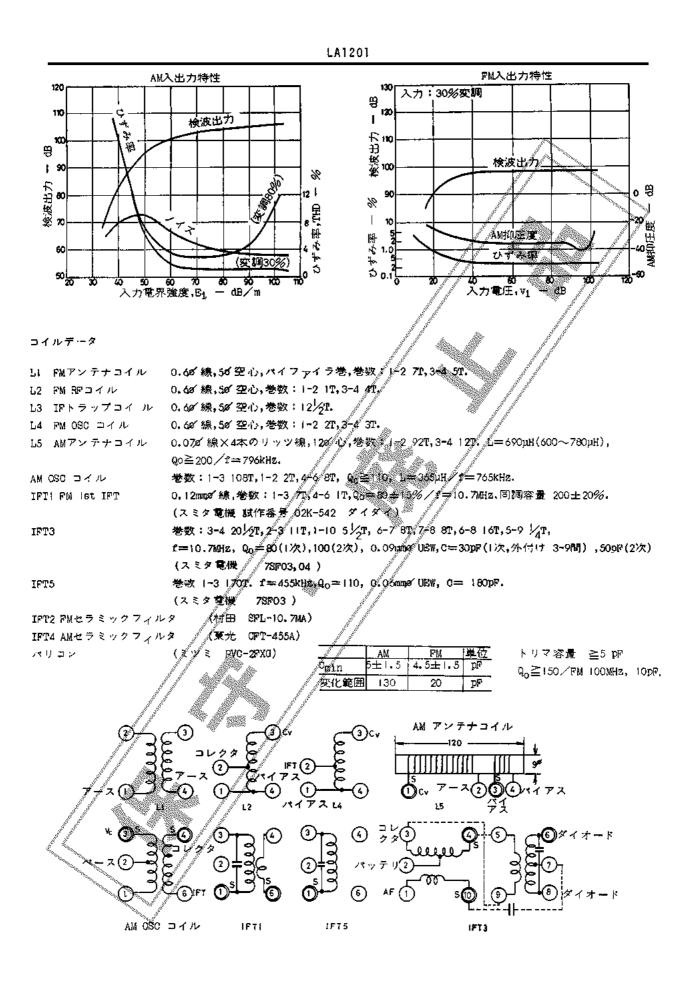
AM 主要特性

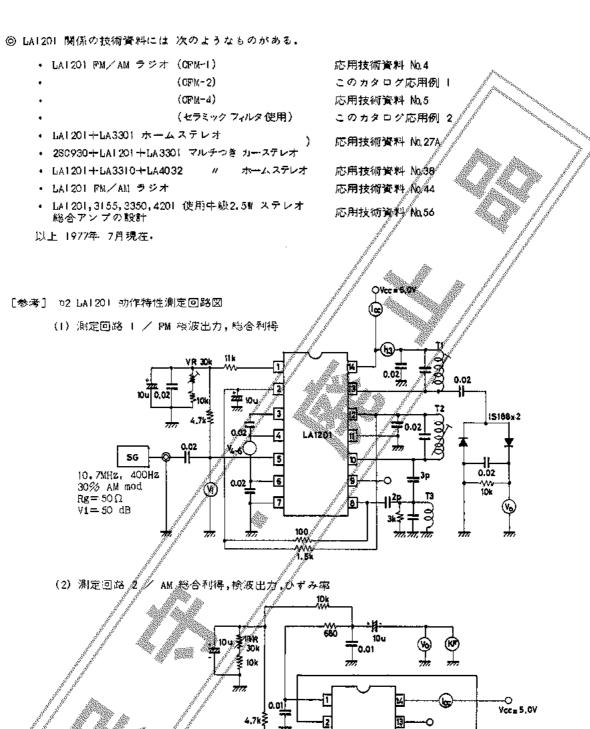
		1 1		
	項目および測定条件。	周波数	測定代	3
i	受信周波数範囲 🦯		530 <u>~1</u> 66) kh e
	最大感度 (検波出力 300時)	600kHz 10CokHz 1400kHz	32 33 30,4	18. n 18. n 19. n
	(そぼ)な田 77 300V9年) 東用,恐)度 (S / N = 20代B) AQC-FOM	SOOKHZ IOQOKHZ I400XHZ	30/ 47/ 48 - 31 51	18/m d8/m d8/m
	AUC-FOM	600kHz	51	dB
	(入力400dB/m時の出 力から出丸が-10dBま		51	đB
	A‴-AN1 ++3™=3%.	1400¥Hz	53	dB
	ひずみ室 (入力746単 90%変調 (入力746単 90%変調	1000kHz	1 3, 2	% %
L.	带城幅(最大感度时)。	1000kHz	5	kHz
		+ 10kHz 1000kHz	26	dB
		- IOkHz	27	dB
	S/N (入力7408時)	1000kHz	43	dB
	and the second se		(1 <i>µ</i> V	=0 dB)

PM 主要特性

項目および測定条件	周波数	測定値	
受信周波数範囲		85~109	MHz
最大感度 (検波出力 3mV時)	88 MHz 98 MHz 108 MHz	0 2 3	dB dB dB
奖 用感度 (S/N=30dB)	88 MHz 98 MHz 108 MHz	10 10 11	dB dB dB
3dB limitting感度	88 MHz 98 MHz 108 MHz		dB dB dB
ひずみ率 (入力52dB 30%変調 100%変調	98 MHz	0.3	% %
6dB down带城幅	98 MHz	200	kHz
実効(2信号)選択度 (入力=40dB)	+400kHz 98 MH2	30	₫₿
	-400kHz	28	₫B
AM抑圧比(入力54dB)	98 MHz	34	d8
S/N (入力=54dB)	98 MHz	53	₫₿

(1 # V ≕ 0 dB)





3

0.02

۷۵۰б

0,02

0.02

1100

0.02

SG

455kHz / 400Hz

30% AM mod Rg=50Ω 12

11

110

9

0.02

LA1201

No.495-10/10





